ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND0.3V to +6.0V All Other Pins to GND0.3V to the lower of (V _{DD} +0.3V) and +6.0V	Continuous Power Dissipation (T _A = +70°C) 16-Pin TQFN (derate 17.5mW/°C above +70°C)1398mW 14-Pin TSSOP (derate 9.1mW/°C above +70°C)727mW
Maximum Continuous Current into H_, W_, and L_ ±5.0mA MAX5487 ±1.3mA MAX5488 ±0.6mA	Operating Temperature Range40°C to +85°C Junction Temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{DD} = +2.7 V \text{ to } +5.25 V, V_{H} = V_{DD}, V_{L} = GND, T_{A} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}, \text{ unless otherwise noted.}$ T_A = +25 $^{\circ}\text{C}$, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
DC PERFORMANCE (Voltage-Div	ider Mode, Fi	gure 1)				•	
Resolution	N		256			Taps	
Integral Nonlinearity	INL	(Note 2)			±1	LSB	
Differential Nonlinearity	DNL	(Note 2)			±0.5	LSB	
Dual-Code Matching		Register A = register B			2	LSB	
End-to-End Resistor Tempco	TCR			35		ppm/°C	
Ratiometric Resistor Tempco				5		ppm/°C	
		MAX5487		3.5	6		
Full-Scale Error		MAX5488		-0.6	+1.2	LSB	
		MAX5489		-0.3	+1.2		
Zero-Scale Error		MAX5487		3.5	6		
		MAX5488		-0.6	1.5	LSB	
		MAX5489		0.3	1		
DC PERFORMANCE (Variable-Re	sistor Mode,	Figure 1)				•	
Resolution			256			Taps	
Integral Nanling with (Nata 2)		V _{DD} = 5.0V			±1.5	LOD	
Integral Nonlinearity (Note 3)		V _{DD} = 3.0V			±3	LSB	
Differential New York (New York)		$V_{DD} = 5.0V$			±1	1.00	
Differential Nonlinearity (Note 3)		V _{DD} = 3.0V			±1	LSB	
DC PERFORMANCE (Resistor Ch	aracteristics)	·				
Missan Desistance (NI-to-4)	Б	V _{DD} = 5.0V		200	350		
Wiper Resistance (Note 4)	Rw	$V_{DD} = 3.0V$		325	675	Ω	
Wiper Capacitance	Cw			50		рF	
		MAX5487	7.5	10	12.5		
End-to-End Resistance	R _{HL}	MAX5488	37.5	50	62.5	kΩ	
		MAX5489	75	100	125	1	

2 ______N/IXI/N

DC ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = +2.7V \text{ to } +5.25V, V_H = V_{DD}, V_L = GND, T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.} Typical values are at <math>V_{DD} = +5.0V, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ (Note 1)

PARAMETER	SYMBOL	CONI	MIN	TYP	MAX	UNITS	
DIGITAL INPUTS	-						•
		$V_{DD} = 3.6V \text{ to } 5.25V$		2.4			
Input High Voltage (Note 5)	VIH	V _{DD} = 2.7V to 3.6V		0.7 x V _{DD}			V
Input Low Voltage	VIL	$V_{DD} = 2.7V \text{ to } 5.25V$	(Note 5)			0.8	V
Input Leakage Current	I _{IN}					±1.0	μΑ
Input Capacitance	CIN				5.0		рF
AC PERFORMANCE		•					
Crosstalk		f _H _ = 1kHz, L_ = GN (Note 6)	D, measurement at W_		-90		dB
			MAX5487		350		
-3dB Bandwidth	BW	Wiper at midscale Cw_ = 10pF	MAX5488		90		kHz
		CW_ = TOPF	MAX5489		45		
Total Harmonic Distortion	THD	V _H _ = 1V _{RMS} at 1kH: measurement at W_	z, L_ = GND,		0.02		%
TIMING CHARACTERISTICS (Analo	og)						
		Code 0 to 127 (Note 7)	MAX5487		0.5		μs
Wiper-Settling Time	ts		MAX5488		0.75		
			MAX5489		1.5		
TIMING CHARACTERISTICS (Digital	al, Figure 2,	Note 8)					
SCLK Frequency						5	MHz
SCLK Clock Period	tcp			200			ns
SCLK Pulse-Width High	tсн			80			ns
SCLK Pulse-Width Low	tCL			80			ns
CS Fall to SCLK Rise Setup	tcss			80			ns
SCLK Rise to CS Rise Hold	tcsh			0			ns
DIN to SCLK Setup	t _{DS}			50			ns
DIN Hold after SCLK	tDH			0			ns
SCLK Rise to CS Fall Delay	tcso			20			ns
CS Rise to SCLK Rise Hold	tcs1			80			ns
CS Pulse-Width High	tcsw			200			ns
Write NV Register Busy Time	tBUSY					12	ms
Read NV Register Access Time	tacc					1	μs
Write Wiper Register to Output Delay	two					1	μs
NONVOLATILE MEMORY RELIABI							•
Data Retention		T _A = +85°C			50		Years
Food was a		T _A = +25°C		200,000			
Endurance		T _A = +85°C			50,000		Stores

DC ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = +2.7V \text{ to } +5.25V, V_{H} = V_{DD}, V_{L} = GND, T_{A} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $V_{DD} = +5.0V, T_{A} = +25^{\circ}\text{C}, \text{ unless otherwise noted.}$ (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLIES						
Power-Supply Voltage	V _{DD}		2.70		5.25	V
Supply Current	I _{DD}	During write cycle only, digital inputs = V _{DD} or GND			400	μΑ
Standby Current		Digital inputs = V _{DD} or GND, T _A = +25°C		0.5	1	μΑ

- Note 1: All devices are production tested at $T_A = +85^{\circ}C$ and are guaranteed by design and characterization for -40°C < T_A < +85°C.
- Note 2: DNL and INL are measured with the potentiometer configured as a voltage-divider with H_ = V_{DD} and L_ = 0. The wiper terminal is unloaded and measured with an ideal voltmeter.
- Note 3: DNL and INL are measured with the potentiometer configured as a variable resistor. H_ is unconnected and L_ = 0. For VDD = +5V, the wiper terminal is driven with a source current of 400μA for the $10k\Omega$ configuration, 80μA for the $50k\Omega$ configuration, and 40μA for the $100k\Omega$ configuration. For VDD = +3V, the wiper terminal is driven with a source current of 200μ A for the $10k\Omega$ configuration, 40μ A for the $50k\Omega$ configuration, and 20μ A for the $100k\Omega$ configuration.
- Note 4: The wiper resistance is the worst value measured by injecting the currents given in Note 3 into W_ with L_ = GND. R_W = (V_W V_H) / I_W.
- Note 5: The device draws higher supply current when the digital inputs are driven with voltages between (V_{DD} 0.5V) and (GND + 0.5V). See Supply Current vs. Digital Input Voltage in the *Typical Operating Characteristics* section.
- Note 6: Wiper at midscale with a 10pF load.
- Note 7: Wiper-settling time is the worst-case 0-to-50% rise time, measured between tap 0 and tap 127. H_ = V_{DD}, L_ = GND, and the wiper terminal is unloaded and measured with a 10pF oscilloscope probe (see Tap-to-Tap Switching Transient in the *Typical Operating Characteristics* section).
- Note 8: Digital timing is guaranteed by design and characterization, and is not production tested.

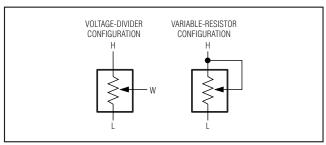
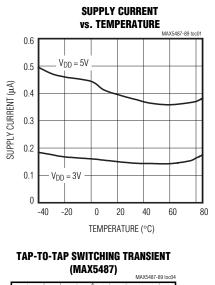
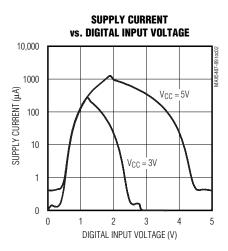


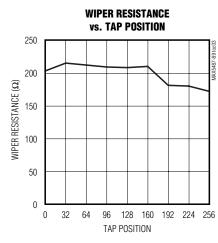
Figure 1. Voltage-Divider/Variable-Resistor Configurations

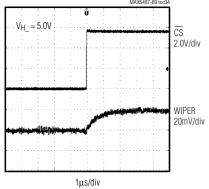
Typical Operating Characteristics

 $(V_{DD} = +5.0V, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

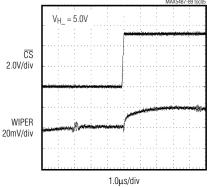




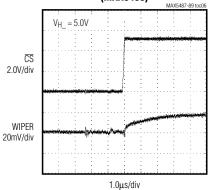




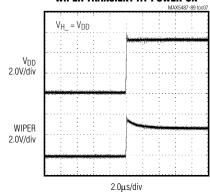




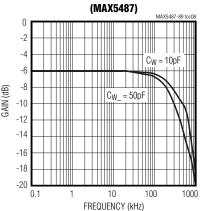
TAP-TO-TAP SWITCHING TRANSIENT (MAX5489)



WIPER TRANSIENT AT POWER-ON

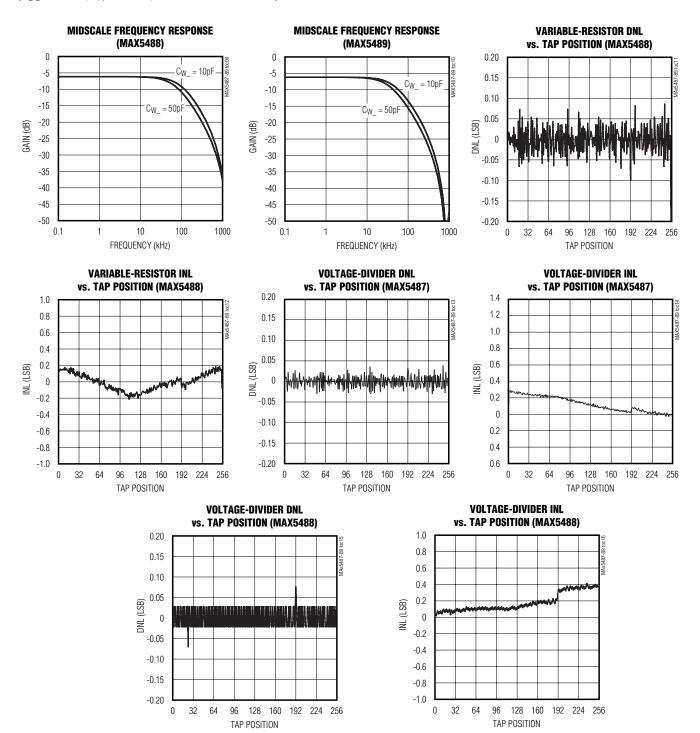


MIDSCALE FREQUENCY RESPONSE



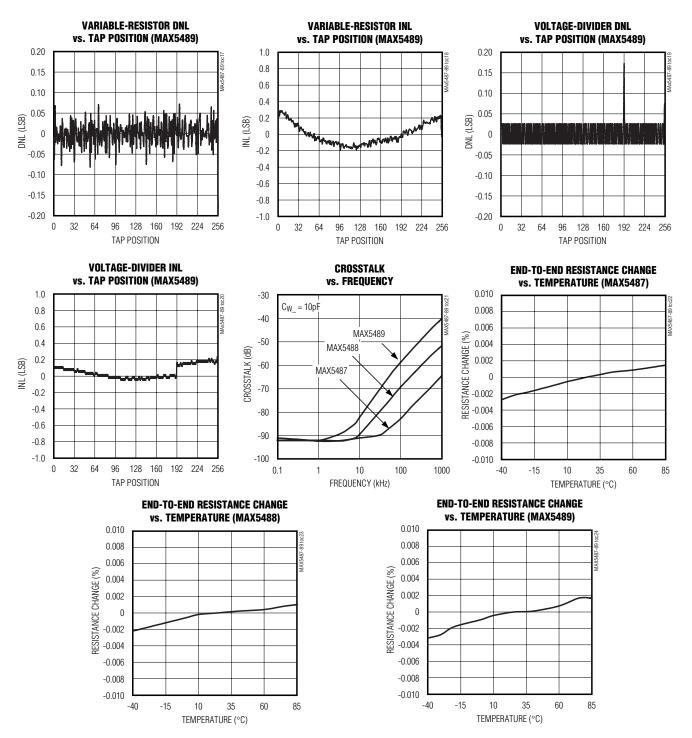
Typical Operating Characteristics (continued)

 $(V_{DD} = +5.0V, T_A = +25^{\circ}C, unless otherwise noted.)$



Typical Operating Characteristics (continued)

 $(V_{DD} = +5.0V, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



Pin Description

Р	PIN		FUNCTION					
TQFN	TSSOP	NAME	FUNCTION					
1	14	V_{DD}	Power Supply. Bypass V _{DD} to GND with a 0.1µF capacitor as close to the device as possible.					
2	13	SCLK	Serial-Interface Clock Input					
3	12	DIN	Serial-Interface Data Input					
4	11	CS	Active-Low Chip-Select Digital Input					
5, 6, 9	7, 9, 10	N.C.	No Connection. Not internally connected.					
7	8	GND	Ground					
8, 16	_	I.C.	Internally connected to EP. Leave unconnected.					
10	6	LB	Low Terminal of Resistor B. The voltage at L can be greater than or less than the voltage at H. Current can flow into or out of L.					
11	5	WB	Wiper Terminal of Resistor B					
12	4	НВ	High Terminal of Resistor B. The voltage at H can be greater than or less than the voltage at L. Current can flow into or out of H.					
13	3	LA	Low Terminal of Resistor A. The voltage at L can be greater than or less than the voltage at H. Current can flow into or out of L.					
14	2	WA	Wiper Terminal of Resistor A					
15	1	НА	High Terminal of Resistor A. The voltage at H can be greater than or less than the voltage at L. Current can flow into or out of H.					
_	_	EP	Exposed Pad (TQFN only). Internally connected to pins 8 and 16. Leave unconnected.					

Detailed Description

The MAX5487/MAX5488/MAX5489 contain two resistor arrays, with 255 resistive elements each. The MAX5487 has an end-to-end resistance of $10k\Omega$, while the MAX5488 and MAX5489 have resistances of $50k\Omega$ and $100k\Omega$, respectively. The MAX5487/MAX5488/MAX5489 allow access to the high, low, and wiper terminals on both potentiometers for a standard voltage-divider configuration. Connect the wiper to the high terminal, and connect the low terminal to ground, to make the device a variable resistor (see Figure 1).

A simple 3-wire serial interface programs either wiper directly to any of the 256 tap points. The nonvolatile memory stores the wiper position prior to power-down and recalls the wiper to the same point upon power-up or by using an interface command (see Table 1). The nonvolatile memory is guaranteed for 200,000 wiper store cycles and 50 years for wiper data retention.

SPI Digital Interface

The MAX5487/MAX5488/MAX5489 use a 3-wire SPI-compatible serial data interface (Figures 2 and 3). This write-only interface contains three inputs: chip-select

(\overline{CS}), data clock (SCLK), and data in (DIN). Drive \overline{CS} low to enable the serial interface and clock data synchronously into the shift register on each SCLK rising edge.

The WRITE commands (C1, C0 = 00 or 01) require 16 clock cycles to clock in the command, address, and data (Figure 3a). The COPY commands (C1, C0 = 10, 11) can use either eight clock cycles to transfer only command and address bits (Figure 3b) or 16 clock cycles, with the device disregarding 8 data bits (Figure 3a).

After loading data into the shift register, drive \overline{CS} high to latch the data into the appropriate potentiometer control register and disable the serial interface. Keep \overline{CS} low during the entire serial data stream to avoid corruption of the data.

Digital-Interface Format

The data format consists of three elements: command bits, address bits, and data bits (see Table 1 and Figure 3). The command bits (C1 and C0) indicate the action to be taken such as changing or storing the wiper position. The address bits (A1 and A0) specify which potentiometer the command affects and the 8 data bits (D7 to D0) specify the wiper position.

Table 1. Register Map

OLOOK EDGE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
CLOCK EDGE	_	_	C1	C0	_	_	A1	A0	D7	D6	D5	D4	D3	D2	D1	D0
Write Wiper Register A	0	0	0	0	0	0	0	1	D7	D6	D5	D4	D3	D2	D1	D0
Write Wiper Register B	0	0	0	0	0	0	1	0	D7	D6	D5	D4	D3	D2	D1	D0
Write NV Register A	0	0	0	1	0	0	0	1	D7	D6	D5	D4	D3	D2	D1	D0
Write NV Register B	0	0	0	1	0	0	1	0	D7	D6	D5	D4	D3	D2	D1	D0
Copy Wiper Register A to NV Register A	0	0	1	0	0	0	0	1	_	_		_	_	_	_	_
Copy Wiper Register B to NV Register B	0	0	1	0	0	0	1	0	_	_	_	_	_	_	_	_
Copy Both Wiper Registers to NV Registers	0	0	1	0	0	0	1	1	_	_	_	_	_	_	_	_
Copy NV Register A to Wiper Register A	0	0	1	1	0	0	0	1	_	_	_	_	_	_	_	_
Copy NV Register B to Wiper Register B	0	0	1	1	0	0	1	0	_	_		_	_	_	_	_
Copy Both NV Registers to Wiper Registers	0	0	1	1	0	0	1	1	_	_	_	_	_	_	_	_

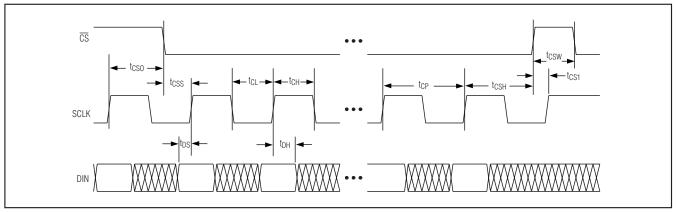


Figure 2. Timing Diagram

Write-Wiper Register (Command 00)

Data written to the write-wiper registers (C1, C0 = 00) controls the wiper positions. The 8 data bits (D7 to D0) indicate the position of the wiper. For example, if DIN = 0000 0000, the wiper moves to the position closest to L_{-} . If DIN = 1111 1111, the wiper moves closest to H_{-} .

This command writes data to the volatile RAM, leaving the NV registers unchanged. When the device powers up, the data stored in the NV registers transfers to the volatile wiper register, moving the wiper to the stored position.

Write-NV Register (Command 01)

This command (C1, C0 = 01) stores the position of the wipers to the NV registers for use at power-up. Alternatively, the "copy wiper register to NV register" command can be used to store the position of the wipers to the NV registers. Writing to the NV registers does not affect the position of the wipers.

Copy Wiper Register to NV Register (Command 10) This command (C1, C0 = 10) stores the current position of the wiper to the NV register, for use at power-up. This command may affect one potentiometer at a time,

10

Dual, 256-Tap, Nonvolatile, SPI-Interface, Linear-Taper Digital Potentiometers

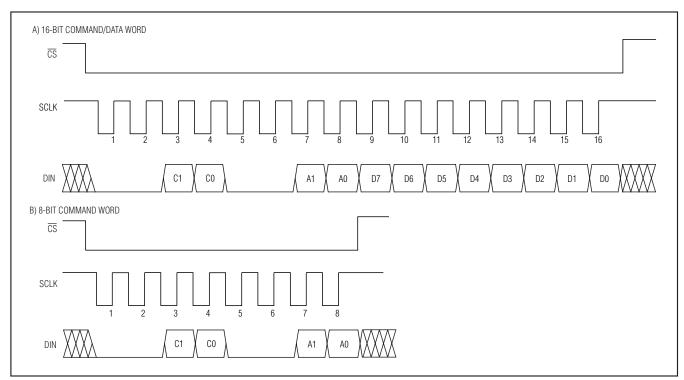


Figure 3. Digital-Interface Format

or both simultaneously, depending on the state of A1 and A0. Alternatively, the "write NV register" command can be used to store the current position of the wiper to the NV register.

Copy NV Register to Wiper Register (Command 11)

This command (C1, C0 = 11) restores the wiper position to the previously stored position in the NV register. This command may affect one potentiometer at a time, or both simultaneously, depending on the state of A1 and A0.

Nonvolatile Memory

The internal EEPROM consists of a nonvolatile register that retains the last stored value prior to power-down. The nonvolatile register is programmed to midscale at the factory. The nonvolatile memory is guaranteed for 200,000 wiper write cycles and 50 years for wiper data retention.

Power-Up

Upon power-up, the MAX5487/MAX5488/MAX5489 load the data stored in the nonvolatile wiper register into the volatile memory register, updating the wiper position with the data stored in the nonvolatile wiper register. This initialization period takes 5µs.

Standby

The MAX5487/MAX5488/MAX5489 feature a low-power standby mode. When the device is not being programmed, it enters into standby mode and supply current drops to $0.5\mu A$ (typ).

_Applications Information

The MAX5487/MAX5488/MAX5489 are ideal for circuits requiring digitally controlled adjustable resistance, such as LCD contrast control (where voltage biasing adjusts the display contrast), or for programmable filters with adjustable gain and/or cutoff frequency.

Positive LCD Bias Control

Figures 4 and 5 show an application where the MAX5487/MAX5488/MAX5489 provide an adjustable, positive LCD-bias voltage. The op amp provides buffering and gain to the resistor-divider network made by the potentiometer (Figure 4) or by a fixed resistor and a variable resistor (Figure 5).

Programmable Filter

Figure 6 shows the MAX5487/MAX5488/MAX5489 in a 1st-order programmable-filter application. Adjust the gain of the filter with R₂, and set the cutoff frequency with R₃.

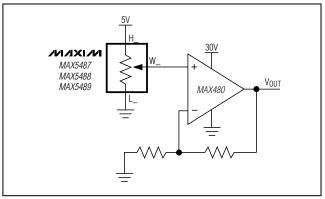


Figure 4. Positive LCD-Bias Control Using a Voltage-Divider

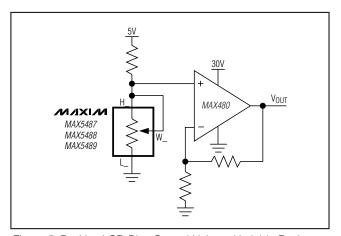


Figure 5. Positive LCD-Bias Control Using a Variable Resistor

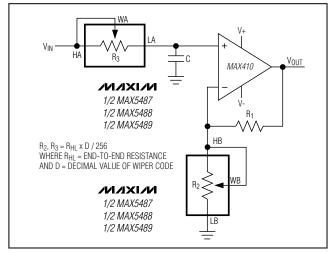


Figure 6. Programmable Filter

Use the following equations to calculate the gain (A) and the -3dB cutoff frequency (fc):

$$A = 1 + \frac{R_1}{R_2}$$

$$f_C = \frac{1}{2\pi \times R_3 \times C}$$

Adjustable Voltage Reference

Figure 7 shows the MAX5487/MAX5488/MAX5489 used as the feedback resistors in multiple adjustable voltage-reference applications. Independently adjust the output voltages of the MAX6160s from 1.23V to V_{IN} - 0.2V by changing the wiper positions of the MAX5487/MAX5488/MAX5489.

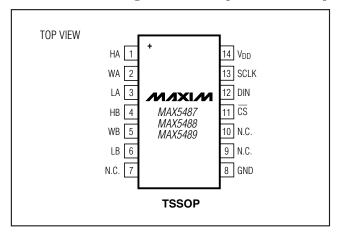
Offset Voltage and Gain Adjustment

Connect the high and low terminals of one potentiometer of a MAX5487/MAX5488/MAX5489 to the NULL inputs of a MAX410, and connect the wiper to the op amp's positive supply to nullify the offset voltage over the operating temperature range. Install the other potentiometer in the feedback path to adjust the gain of the MAX410 (see Figure 8).

_Chip Information

PROCESS: BiCMOS

Pin Configurations (continued)



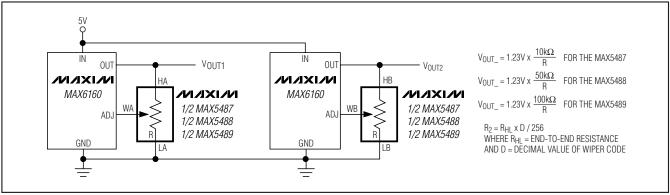


Figure 7. Adjustable Voltage Reference

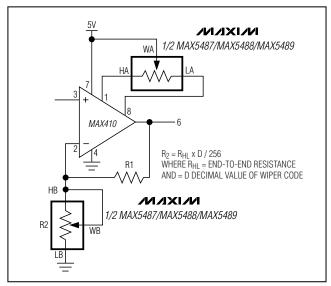


Figure 8. Offset Voltage and Gain Adjustment

Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE	PACKAGE	OUTLINE	LAND
TYPE	CODE	NO.	PATTERN NO.
16 TQFN-EP	T1633F+3	21-0136	90-0033
14 TSSOP	U14+1	<u>21-0066</u>	90-0113

Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE	END-TO-END RESISTANCE ($k\Omega$)	TOP MARK
MAX5488ETE+	-40°C to +85°C	16 TQFN-EP*	50	ABS
MAX5488EUD+	-40°C to +85°C	14 TSSOP	50	_
MAX5489ETE+	-40°C to +85°C	16 TQFN-EP*	100	ABT
MAX5489EUD+	-40°C to +85°C	14 TSSOP	100	_
MAX5489ETE/V+	-40°C to +85°C	16 TQFN-EP*	100	AIE

^{*}EP = Exposed pad.

⁺Denotes a lead(Pb)-free/RoHS-compliant package.

[/]V denotes an automotive qualified part.

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
3	1/07	_	1, 8, 12, 15
4	4/10	Updated <i>Ordering Information</i> (added lead-free packaging and automotive qualified part, released TSSOP package), and updated <i>Absolute Maximum Ratings</i>	1, 2, 12

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Maxim Integrated:

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